

# 2SK43,43S

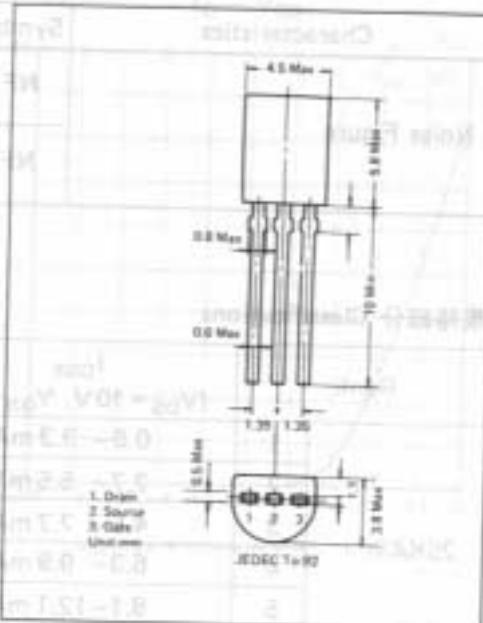
Industrial Use

## Silicon N-Channel Junction FET

- Super Low Noise, High Gm, High Reliability
- プリアンプ(TVカメラ、VTR、オーディオ、測定器)
- アナログスイッチ(2SK43S-D,  $R_{ON} \leq 80\Omega$ )
- 小リーク電流( $I_{GSS} = -5\text{pA}$  typ.)
- TV Camera, Video and Audio Preamplifiers
- Analogue Switchings (2SK43S-D)
- Small Leak Current ( $I_{GSS} = -5\text{pA}$  typ.)

绝对最大定格 Absolute Maximum Ratings  $T_a = 25^\circ\text{C}$ 

Characteristics	Symbol	2SK43/2SK43S
Drain-to-Gate Voltage	$V_{DGG}$	30V
Source-to-Gate Voltage	$V_{SGG}$	50V
Drain Current	$I_D$	20 mA
Gate Current	$I_G$	5 mA
Power Dissipation	$P$	300 mW
Junction Temperature	$T_J$	100°C
Storage Temperature	$T_{STG}$	-50~+120°C

电气的特性 Electrical Characteristics  $T_a = 25^\circ\text{C}$ 

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-to-Gate Voltage	$V_{DGS}$	$I_G = 10\mu\text{A}, V_{DS} = 0$	25			V
Gate Cutoff Current	$I_{GSS}$	$V_{GS} = -15\text{V}, V_{DS} = 0$ 2SK43			-1.0	nA
Drain Saturation Current	$I_{DS(on)}$	$V_{DS} = 10\text{V}, V_{GS} = 0$	0.9		14.3	mA
Pinch-off Voltage	$V_p$	$V_{DS} = 10\text{V}, I_D = 30\mu\text{A}$	0.18		1.49	V
Forward Transfer Conductance	$G_m$	$V_{DS} = 10\text{V}, V_{GS} = 0, f = 1\text{kHz}$	6.3			$\text{m}\Omega$
Input Impedance Y11S	$r_i$	$V_{DS} = 10\text{V}, V_{GS} = 0, f = 100\text{MHz}$		1.2		$\text{k}\Omega$
Output Impedance Y22S	$C_o$	$V_{DS} = 10\text{V}, V_{GS} = 0, f = 100\text{MHz}$		13		pF
Reverse Transfer Capacitance	$C_{dss}$	$V_{DS} = 10\text{V}, V_{GS} = 0, f = 1\text{MHz}$		2.7		pF
Gate-to-Drain Capacitance	$C_{GD}$	$V_{GS} = 0, f = 1\text{MHz}$ , Fig. 1		7		pF
Gate-to-Source Capacitance	$C_{GS}$	$V_{GD} = 0, f = 1\text{MHz}$ , Fig. 2		7		pF
Off-State Resistance	$R_{OFF}$	2SK43S-D	$10^9$	$10^{12}$		$\Omega$
n-State Resistance	$R_{ON}$	Ref. □ Table 1			80	$\Omega$
Input Noise Voltage	$e$	$V_{GS} = 0, V_{DS} = 10\text{V}, R_g = 10\text{k}\Omega, f = 1\text{kHz}$		13		$\text{nV}/\text{Hz}^{1/2}$
	$e$	$V_{GS} = 0, V_{DS} = 10\text{V}, R_g = 100\text{k}\Omega, f = 10\text{Hz}$		39		$\text{nV}/\text{Hz}^{1/2}$

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Noise Figure	NF	$V_{GS} = 0$ , $V_{DS} = 10V$ , $R_g = 10 k\Omega$ , $f = 1 kHz$		0.1		dB
	NF	$V_{GS} = 0$ , $V_{DS} = 10V$ , $R_g = 100 k\Omega$ , $f = 10 Hz$		0.1		dB

## 規格細分 Classifications

Rank	$I_{DS}$ ( $V_{DS} = 10V$ , $V_{GS} = 0$ )	$V_p$ ( $V_{DS} = 10V$ , $I_D = 30 \mu A$ )	$R_m$ ( $V_{DS} = 10V$ , $f = 1 kHz$ )	$R_{ON}$ $R_{OFF}$
2SK43-	1	0.9– 3.3 mA	0.18–0.61 V	6.3 mΩ –
	2	2.7– 5.5 mA	0.36–0.83 V	6.3 mΩ –
	3	4.5– 7.7 mA	0.45–0.99 V	10.8 mΩ –
	4	6.3– 9.9 mA	0.58–1.21 V	10.8 mΩ –
	5	8.1–12.1 mA	0.72–1.38 V	12.6 mΩ –
	6	9.9–14.3 mA	0.85–1.49 V	12.6 mΩ –
2SK43S-	A	0.9– 3.3 mA	0.18–0.61 V	6.3 mΩ –
	B	2.7– 5.5 mA	0.36–0.83 V	6.3 mΩ –
	C	4.5– 9.9 mA	0.45–1.21 V	10.8 mΩ –
	D	8.1–14.3 mA	0.72–1.49 V	14.0 mΩ –

Table 1 2SK43S-D  $R_{ON}$ ,  $R_{OFF}$  Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
On-State Resistance	$R_{ON}$	$V_{DS} = 0.1V$ , $V_{GS} = 0$			80	Ω
Distribution of $R_{ON}$	$\Delta R_{ON}$	$ R_{ON(max)} - R_{ON(min)} $			±17.5	Ω
Off-State Resistance	$R_{OFF}$	$V_{DS} = 10V$ , $V_{GS} = -15V$	$10^9$	$10^{12}$		Ω

